# 9DBV0841

# **RENESAS** 8-Output 1.8V PCIe Zero-Delay/Fanout Clock Buffer with Zo = 100ohms

### DATASHEET

### Description

The 9DBV0841 is a 1.8V member of Renesas' full featured PCIe family. It has integrated output terminations providing Zo =  $100\Omega$  for direct connection for  $100\Omega$  transmission lines. The device has 8 output enables for clock management and 3 selectable SMBus addresses.

### **Typical Applications**

SSD, microServers, WLAN Access points

### **Output Features**

• Eight 1–200MHz Low-Power (LP) HCSL DIF pairs

### **Key Specifications**

- DIF cycle-to-cycle jitter < 50ps
- DIF output-to-output skew < 50ps
- PCIe Gen5 CC additive phase jitter < 40fs RMS
- 12kHz–20MHz additive phase jitter = 156fs RMS at 156.25M (typical)

### Features/Benefits

- LP-HCSL outputs save 32 resistors; minimal board space and BOM cost
- 62mW typical power consumption in PLL mode; eliminates thermal concerns
- Spread Spectrum (SS) compatible; allows use of SS for EMI reduction
- OE# pins; support DIF power management
- HCSL compatible differential input; can be driven by common clock sources
- Programmable Slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- Pin/software selectable PLL bandwidth and PLL Bypass; minimize phase jitter for each application
- Outputs blocked until PLL is locked; clean system start-up
- Software selectable 50MHz or 125MHz PLL operation; useful for Ethernet applications
- Configuration can be accomplished with strapping pins; SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 6 × 6 mm 48-VFQFPN; minimal board space
- Selectable SMBus addresses; multiple devices can easily share an SMBus segment



### Block Diagram

### **Pin Configuration**



#### 48-pin VFQFPN, 6x6 mm, 0.4mm pitch

- ^v prefix indicates internal 120KOhm pull up AND pull down resistor (biased to VDD/2)
- v prefix indicates internal 120KOhm pull down resistor
- prefix indicates internal 120KOhm pull up resistor

#### **SMBus Address Selection Table**

	SADR	Address	+ Read/Write bit
State of SADR on first application of	0	1101011	x
CKPWRGD PD#	М	1101100	x
CKPWRGD_PD#	1	1101101	x

#### **Power Management Table**

CKPWRGD PD#	CLK_IN	SMBus OEx# Pin		DIF	PLL	
		OEx bit		True O/P	Comp. O/P	FLL
0	Х	Х	Х	Low	Low	Off
1	Running	0	Х	Low	Low	On <sup>1</sup>
1	Running	1	0	Running	Running	On <sup>1</sup>
1	Running	1	1	Low	Low	On <sup>1</sup>

1. If Bypass mode is selected, the PLL will be off, and outputs will be running.

#### **Power Connections**

Pin Number			Description
VDD	VDDIO	GND	Description
			Input
5		8	
			analog
12		9	<b>Digital Power</b>
20, 31, 38	13, 21, 31, 39, 47	22, 29, 40	DIF outputs
30		29	PLL Analog

#### **Frequency Select Table**

FSEL	CLK_IN	DIFx								
Byte3 [4:3]	(MHz)	(MHz)								
00 (Default)	100.00	CLK_IN								
01	50.00	CLK_IN								
10	125.00	CLK_IN								
11	Reserved	Reserved								

#### PLL Operating Mode

		Byte1 [7:6]	Byte1 [4:3]
HiBW_BypM_LoBW#	MODE	Readback	Control
0	PLL Lo BW	00	00
М	Bypass	01	01
1	PLL Hi BW	11	11

### **Pin Descriptions**

PIN #	PIN NAME	TYPE	DESCRIPTION
1		LATCHED	Tri level lateb to aplent SMPus Address - See SMPus Address Selection Table
1	vSADR_tri	IN	Tri-level latch to select SMBus Address. See SMBus Address Selection Table.
2	^vHIBW_BYPM_LOBW#	LATCHED	Trilevel input to select High BW, Bypass or Low BW mode.
2		IN	See PLL Operating Mode Table for Details.
3	FB_DNC	DNC	True clock of differential feedback. The feedback output and feedback input are
3		DNC	connected internally on this pin. Do not connect anything to this pin.
		DNIO	Complement clock of differential feedback. The feedback output and feedback
4	FB_DNC#	DNC	input are connected internally on this pin. Do not connect anything to this pin.
			1.8V power for differential input clock (receiver). This VDD should be treated as
5	VDDR1.8	PWR	an Analog power rail and filtered appropriately.
6	CLK IN	IN	True Input for differential reference clock.
7	CLK IN#	IN	Complementary Input for differential reference clock.
8	GNDR	GND	Analog Ground pin for the differential input (receiver)
9	GNDDIG	GND	Ground pin for digital circuitry
10	SCLK 3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
11	SDATA 3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
12	VDDDIG1.8	PWR	1.8V digital power (dirty power)
13	VDDIO	PWR	Power supply for differential outputs
			Active low input for enabling DIF pair 0. This pin has an internal pull-down.
14	vOE0#	IN	1 =disable outputs, 0 = enable outputs
15	DIF0	OUT	Differential true clock output
16	DIF0#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 1. This pin has an internal pull-down.
17	vOE1#	IN	1 =disable outputs, 0 = enable outputs
18	DIF1	OUT	Differential true clock output
19	DIF1#	OUT	Differential Complementary clock output
20	VDD1.8	PWR	Power supply, nominal 1.8V
21	VDDIO	PWR	Power supply for differential outputs
22	GND	GND	Ground pin.
23	DIF2	OUT	Differential true clock output
24	DIF2#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 2. This pin has an internal pull-down.
25	vOE2#	IN	1 =disable outputs, 0 = enable outputs
26	DIF3	OUT	Differential true clock output
27	DIF3#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 3. This pin has an internal pull-down.
28	vOE3#	IN	1 =disable outputs, 0 = enable outputs
29	GNDA	GND	Ground pin for the PLL core.
30	VDDA1.8	PWR	1.8V power for the PLL core.
31	VDDIO	PWR	Power supply for differential outputs
32	DIF4	OUT	Differential true clock output
33	DIF4#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 4. This pin has an internal pull-down.
34	vOE4#	IN	1 =disable outputs, 0 = enable outputs
35	DIF5	OUT	Differential true clock output
36	DIF5#	OUT	Differential Complementary clock output
			Active low input for enabling DIF pair 5. This pin has an internal pull-down.
37	vOE5#	IN	1 = disable outputs, 0 = enable outputs
38	VDD1.8	PWR	Power supply, nominal 1.8V
l			

		-	
PIN #	PIN NAME	TYPE	DESCRIPTION
39	VDDIO	PWR	Power supply for differential outputs
40	GND	GND	Ground pin.
41	DIF6	OUT	Differential true clock output
42	DIF6#	OUT	Differential Complementary clock output
43	vOE6#	IN	Active low input for enabling DIF pair 6. This pin has an internal pull-down.
43	VOE0#		1 =disable outputs, 0 = enable outputs
44	DIF7	OUT	Differential true clock output
45	DIF7#	OUT	Differential Complementary clock output
46	vOE7#	IN	Active low input for enabling DIF pair 7. This pin has an internal pull-down.
40	VOE7#		1 =disable outputs, 0 = enable outputs
47	VDDIO	PWR	Power supply for differential outputs
			Input notifies device to sample latched inputs and start up on first high
48	^CKPWRGD_PD#	IN	assertion. Low enters Power Down Mode, subsequent high assertions exit
			Power Down Mode. This pin has internal pull-up resistor.
49	epad	GND	Connect epad to ground

### Pin Descriptions (cont.)

### **Test Loads**



#### L = 5 inches

### **Alternate Terminations**

The 9DBV family can easily drive LVPECL, LVDS, and CML logic. See <u>"AN-891 Driving LVPECL, LVDS, and CML Logic with</u> <u>"Universal" Low-Power HCSL Outputs</u>" for details.

### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the 9DBV0841. These ratings, which are standard values for Renesas commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDDxx	Applies to VDD, VDDA and VDDIO	-0.5		2.5	V	1,2
Input Voltage	V <sub>IN</sub>		-0.5		V <sub>DD</sub> +0.5V	V	1, 3
Input High Voltage, SMBus	VIHSMB	SMBus clock and data pins			3.6V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>3</sup> Not to exceed 2.5V.

### **Electrical Characteristics–Clock Input Parameters**

TA = T<sub>AMB.</sub> Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Common Mode Voltage - DIF_IN	V <sub>COM</sub>	Common Mode Input Voltage	150		1000	mV	1
Input Swing - DIF_IN	V <sub>SWING</sub>	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{DD}$ , $V_{IN} = GND$	-5		5	uA	
Input Duty Cycle	d <sub>tin</sub>	Measurement from differential waveform	45		55	%	1
Input Jitter - Cycle to Cycle	J <sub>DIFIn</sub>	Differential Measurement	0		125	ps	1

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>Slew rate measured through +/-75mV window centered around differential zero.

# Electrical Characteristics–Input/Supply/Common Parameters–Normal Operating Conditions

TA =  $T_{AMB}$ , Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTE
Supply Voltage	VDDx	Supply voltage for core and analog	1.7	1.8	1.9	V	
Output Supply Voltage	VDDIO	Supply voltage for Low Power HCSL Outputs	0.9975	1.05	1.9	V	
Ambient Operating	т	Commercial range	0	25	70	°C	
Temperature	T <sub>AMB</sub>	Industrial range	-40	25	85	°C	
Input High Voltage	V <sub>IH</sub>	Single-ended inputs, except SMBus	$0.75 V_{DD}$		V <sub>DD</sub> + 0.3	V	
Input Mid Voltage	V <sub>IM</sub>	Single-ended tri-level inputs ('_tri' suffix)	$0.4 V_{DD}$		$0.6 V_{DD}$	V	
Input Low Voltage	V <sub>IL</sub>	Single-ended inputs, except SMBus	-0.3		$0.25 V_{DD}$	V	
	l <sub>IN</sub>	Single-ended inputs, $V_{IN}$ = GND, $V_{IN}$ = VDD	-5		5	uA	
Input Current	I <sub>INP</sub>	Single-ended inputs $V_{IN}$ = 0 V; Inputs with internal pull-up resistors $V_{IN}$ = VDD; Inputs with internal pull-down resistors	-200		200	uA	
	F <sub>ibyp</sub>	Bypass mode	1		200	MHz	2
Innut Fraguanay	F <sub>ipll</sub>	100MHz PLL mode	60	100.00	140	MHz	2
Input Frequency	F <sub>ipll</sub>	125MHz PLL mode	75	125.00	175	MHz	2
	F <sub>ipll</sub>	50MHz PLL mode	30	50.00	65	MHz	2
Pin Inductance	L <sub>pin</sub>				7	nH	1
	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	$C_{\text{INDIF}_{\text{IN}}}$	DIF_IN differential clock inputs	1.5		2.7	pF	1,5
	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.6	1	ms	1,2
Input SS Modulation Frequency PCle	f <sub>MODINPCIe</sub>	Allowable Frequency for PCle Applications (Triangular Modulation)	30		33	kHz	
Input SS Modulation Frequency non-PCle	f <sub>MODIN</sub>	Allowable Frequency for non-PCle Applications (Triangular Modulation)	0		66	kHz	
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	1		3	clocks	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t <sub>F</sub>	Fall time of single-ended control inputs			5	ns	2
Trise	t <sub>R</sub>	Rise time of single-ended control inputs				ns	2
SMBus Input Low Voltage	VILSMB	$V_{DDSMB}$ = 3.3V, see note 4 for $V_{DDSMB}$ < 3.3V			0.6	V	
SMBus Input High Voltage	VIHSMB	$V_{DDSMB}$ = 3.3V, see note 5 for $V_{DDSMB}$ < 3.3V	2.1		3.6	V	4
MBus Output Low Voltage	VOLSMB	@ I <sub>PULLUP</sub>			0.4	V	
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	
Nominal Bus Voltage	V <sub>DDSMB</sub>	Bus Voltage	1.7		3.6	V	
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	6

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup>Control input must be monotonic from 20% to 80% of input swing.

 $^{3}$ Time from deassertion until outputs are > 200 mV.

 $^{4}$  For V<sub>DDSMB</sub> < 3.3V, V<sub>IHSMB</sub> > = 0.8xV<sub>DDSMB</sub>.

<sup>5</sup>DIF\_IN input.

<sup>6</sup>The differential input clock must be running for the SMBus to be active.

### **Electrical Characteristics–Low Power HCSL Outputs**

TA = T<sub>AMB</sub>, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	1.7	2.8	4	V/ns	1,2,3
Siew fale	dV/dt	Scope averaging on, slow setting	1.1	2.1	3.2	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		6.2	20	%	1,2,4
Voltage High	V <sub>HIGH</sub>	Statistical measurement on single-ended signal	660	789	850		7
Voltage Low	$V_{\text{LOW}}$	using oscilloscope math function. (Scope averaging on)		38	150	mV	7
Max Voltage	Vmax	Measurement on single ended signal using		803	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	15			7
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	417	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		13	140	mV	1,6

<sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Measured from differential waveform

<sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

<sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross\_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting  $\Delta$ -Vcross to be smaller than Vcross absolute.

<sup>7</sup> At default SMBus settings.

### **Electrical Characteristics–Current Consumption**

TA = T<sub>AMB</sub>, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DDA</sub>	VDDA+VDDR, PLL Mode, @100MHz		10.6	15	mA	1
	I <sub>DD</sub>	VDD, All outputs active @100MHz		6.1	10	mA	1
	I <sub>DDO</sub>	VDDO, All outputs active @100MHz		30.7	35	mA	1
Powerdown Current	I <sub>DDAPD</sub>	VDDA+VDDR, PLL Mode, @100MHz		0.58	1	mA	1, 2
	I <sub>DDPD</sub>	VDD, Outputs Low/Low		0.81	2	mA	1, 2
	I <sub>DDOPD</sub>	VDDO, Outputs Low/Low		0.00	0.01	mA	1, 2

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Input clock stopped.

### Electrical Characteristics–Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T<sub>AMB</sub>, Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
PLL Bandwidth B		-3dB point in High BW Mode	2	2.7	4	MHz	1,5
FLL Bandwidtin	BW	-3dB point in Low BW Mode	1	1.4	2	MHz	1,5
PLL Jitter Peaking	t <sub>JPEAK</sub>	Peak Pass band Gain		1.1	2	dB	1
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	50.1	55	%	1
Duty Cycle Distortion	t <sub>DCD</sub>	Measured differentially, Bypass Mode @100MHz		0.03	1	%	1,3
Skow Input to Output	t <sub>pdBYP</sub>	Bypass Mode, V <sub>T</sub> = 50%	2800	3625	4500	ps	1
Skew, Input to Output	t <sub>pdPLL</sub>	PLL Mode $V_T = 50\%$	-100	-4	100	ps	1,4
Skew, Output to Output	t <sub>sk3</sub>	V <sub>T</sub> = 50%		39	50	ps	1,4
litter Cycle to sycle	+	PLL mode		14	50	ps	1,2
Jitter, Cycle to cycle	t <sub>jcyc-cyc</sub>	Additive Jitter in Bypass Mode		0.10	25	ps	1,2

<sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

<sup>2</sup> Measured from differential waveform

<sup>3</sup> Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

<sup>4</sup> All outputs at default slew rate

<sup>5</sup> The MIN/TYP/MAX values of each BW setting track each other, i.e., Low BW MAX will never occur with Hi BW MIN.

### Electrical Characteristics–Phase Jitter Parameters – 12kHz to 20MHz

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions. See Test Loads for loading conditions.

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Specification Limit	Units	Notes
12k-20M <i>Additive</i> Phase Jitter, Fan-out Buffer Mode	tjph12k-20MFOB	Fan-out Buffer Mode, SSC OFF, 156.25MHz		156		n/a	fs (rms)	1, 2, 3

Notes:

1. Applies to all differential outputs, guaranteed by design and characterization. See Test Loads for measurement setup details.

2. 12kHz to 20M Hz brick wall filter.

3. For RMS values additive jitter is calculated by solving for b where  $[b = sqrt(c^2 - a^2)]$ , a is rms input jitter and c is rms total jitter.

### Electrical Characteristics–Additive PCIe Phase Jitter for Fanout Buffer Mode<sup>[7]</sup>

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions. See Test Loads for loading conditions.

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Limit	Units	Notes
Additive PCIe Phase Jitter, Fan-out Buffer Mode (Common Clocked Architecture)	tjphPCleG1-CC	PCIe Gen 1 (2.5 GT/s)		1.7	3.0	86	ps (p-p)	1, 2
	4	PCIe Gen 2 Hi Band (5.0 GT/s)		0.033	0.049	3	ps (RMS)	1, 2
	ṫjphPCleG2-CC	PCIe Gen 2 Lo Band (5.0 GT/s)		0.122	0.199	3.1	ps (RMS)	1, 2
	tjphPCleG3-CC	PCIe Gen 3 (8.0 GT/s)		0.059	0.098	1	ps (RMS)	1, 2
	tjphPCleG4-CC	PCIe Gen 4 (16.0 GT/s)		0.059	0.098	0.5	ps (RMS)	1, 2, 3, 4
	tjphPCleG5-CC	PCIe Gen 5 (32.0 GT/s)		0.023	0.038	0.15	ps (RMS)	1, 2, 3, 5
	tjphPCleG1-SRIS	PCIe Gen 1 (2.5 GT/s)		0.175	0.038	n/a	ps (RMS)	1, 2, 6
Additive PCIe Phase litter	tjphPCleG2-SRIS	PCIe Gen 2 (5.0 GT/s)		0.156	0.275	n/a	ps (RMS)	1, 2, 6
Additive PCIe Phase Jitter, Fan-out Buffer Mode (SRIS Architecture)	tjphPCleG3-SRIS	PCIe Gen 3 (8.0 GT/s)		0.041	0.247	n/a	ps (RMS)	1, 2, 6
	tjphPCleG4-SRIS	PCIe Gen 4 (16.0 GT/s)		0.043	0.064	n/a	ps (RMS)	1, 2, 6
	tjphPCleG5-SRIS	PCIe Gen 5 (32.0 GT/s)		0.036	0.066	n/a	ps (RMS)	1, 2, 6

Notes:

1. The Refclk jitter is measured after applying the filter functions found in PCI Express Base Specification 5.0, Revision 1.0. See the Test Loads section of the data sheet for the exact measurement setup. The total Ref Clk jitter limits for each data rate are listed for convenience. The worst case results for each data rate are summarized in this table. If oscilloscope data is used, equipment noise is removed from all results.

2. Jitter measurements shall be made with a capture of at least 100,000 clock cycles captured by a real-time oscilloscope (RTO) with a sample rate of 20 GS/s or greater. Broadband oscilloscope noise must be minimized in the measurement. The measured PP jitter is used (no extrapolation) for RTO measurements. Alternately - Jitter measurements may be used with a Phase Noise Analyzer (PNA) extending (flat) and integrating and folding the frequency content up to an offset from the carrier frequency of at least 200 M Hz (at 300 M Hz absolute frequency) below the Nyquist frequency. For PNA measurements for the 2.5 GT/s data rate, the RMS jitter is converted to peak to peak jitter using a multiplication factor of 8.83. In the case where real-time oscilloscope and PNA measurements have both been done and produce different results the RTO result must be used.

3. SSC spurs from the fundamental and harmonics are removed up to a cutoff frequency of 2 MHz taking care to minimize removal of any non-SSC content.

4. Note that 0.7 ps RMS is to be used in channel simulations to account for additional noise in a real system.

5. Note that 0.25 ps RMS is to be used in channel simulations to account for additional noise in a real system.

6. The PCI Express Base Specification 5.0, Revision 1.0 provides the filters necessary to calculate SRIS jitter values, however, it does not provide specification limits, hence the n/a in the Limit column. SRIS values are informative only. In general, a clock operating in an SRIS system must be twice as good as a clock operating in a Common Clock system. For RMS values, twice as good is equivalent to dividing the CC value by  $\sqrt{2}$ . And additional consideration is the value for which to divide by  $\sqrt{2}$ . The conservative approach is to divide the ref clock jitter limit, and the case can be made for dividing the channel simulation values by  $\sqrt{2}$ , if the ref clock is close to the Tx clock input. An example for Gen4 is as follows. A "rule-of-thumb" SRIS limit would be either 0.5ps RMS/ $\sqrt{2}$  = 0.35ps RMS if the clock chip is far from the clock input.

7. Additive jitter for RMS values is calculated by solving for b where  $b = \sqrt{(c^2 - a^2)}$ , and a is rms input jitter and c is rms output jitter.

### **General SMBus Serial Interface Information**

#### How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will **acknowledge**
- Controller (host) sends the byte count = X
- Renesas clock will **acknowledge**
- Controller (host) starts sending Byte N through Byte N+X-1
- Renesas clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock V	Vrite Operation
Controll	er (Host)		Renesas (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnir	ig Byte N		
			ACK
0		$\times$	
0		X Byte	0
0		Ō	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: SMBus Address is Latched on SADR pin.

#### How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- Renesas clock will acknowledge
- Controller (host) sends the beginning byte location = N
- Renesas clock will acknowledge
- Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- Renesas clock will acknowledge
- Renesas clock will send the data byte count = X
- Renesas clock sends Byte N+X-1
- Renesas clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block R	lead C	peration
Co	ntroller (Host)		Renesas
Т	starT bit	-	
SI	ave Address	-	
WR	WRite	-	
		-	ACK
Begi	nning Byte = N		
		-	ACK
RT	Repeat starT	-	
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		e	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
Ν	Not acknowledge		
Р	stoP bit		

#### SMBus Table: Output Enable Register <sup>1</sup>

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7	DIF OE7	Output Enable	RW	Low/Low	OE7# control	1
Bit 6	DIF OE6	Output Enable	RW	Low/Low	OE6# control	1
Bit 5	DIF OE5	Output Enable	RW	Low/Low	OE5# control	1
Bit 4	DIF OE4	Output Enable	RW	Low/Low	OE4# control	1
Bit 3	DIF OE3	Output Enable	RW	Low/Low	OE3# control	1
Bit 2	DIF OE2	Output Enable	RW	Low/Low	OE2# control	1
Bit 1	DIF OE1	Output Enable	RW	Low/Low	OE1# control	1
Bit 0	DIF OE0	Output Enable	RW	Low/Low	OE0# control	1

1. A low on these bits will override the OE# pin and force the differential output Low/Low

#### SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7	PLLMODERB1	PLL Mode Readback Bit 1	R	See PLL Operating Mode Table		Latch
Bit 6	PLLMODERB0	PLL Mode Readback Bit 0	R			Latch
Bit 5	PLLMODE_SWCNTRL	Enable SW control of PLL Mode	RW	Values in B1[7:6] set PLL Mode	Values in B1[4:3] set PLL Mode	0
Bit 4	PLLMODE1	PLL Mode Control Bit 1	RW <sup>1</sup>	See PLL Operat	0	
Bit 3	PLLMODE0	PLL Mode Control Bit 0	RW <sup>1</sup>	See PLL Operat	ling wode Table	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10= 0.8V	11 = 0.9V	0

1. B1[5] must be set to a 1 for these bits to have any effect on the part.

#### SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7	SLEWRATESEL DIF7	Adjust Slew Rate of DIF7	RW	Slow setting	Fast setting	1
Bit 6	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow setting	Fast setting	1
Bit 5	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow setting	Fast setting	1
Bit 4	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow setting	Fast setting	1
Bit 3	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow setting	Fast setting	1
Bit 2	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow setting	Fast setting	1
Bit 1	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow setting	Fast setting	1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow setting	Fast setting	1

#### SMBus Table: Frequency Select Control Register

Byte 3	Name	Control Function	Туре	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	FREQ_SEL_EN	Enable SW selection of frequency	RW	SW frequency change disabled	SW frequency change enabled	0	
Bit 4	FSEL1	Freq. Select Bit 1	RW <sup>1</sup>	See Frequency	0		
Bit 3	FSEL0	Freq. Select Bit 0	RW <sup>1</sup>	See Trequenc		0	
Bit 2		Reserved				1	
Bit 1	Reserved					1	
Bit 0	SLEWRATESEL FB	Adjust Slew Rate of FB	RW	Slow setting	Fast setting	1	

1. B3[5] must be set to a 1 for these bits to have any effect on the part.

#### Byte 4 is Reserved and reads back 'hFF

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R		0	
Bit 6	RID2	Revision ID	R	A rov -	0	
Bit 5	RID1	Revision ID	R	A rev = 0000		0
Bit 4	RID0		R			0
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001	0001 = IDT	
Bit 1	VID1	VENDORID	R	0001 – 101		0
Bit 0	VID0		R			1

#### SMBus Table: Revision and Vendor ID Register

#### SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx,	01 = DBx,	0
Bit 6	Device Type0	Device Type	R	10 = DMx, 1	1	
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R			0
Bit 3	Device ID3	Device ID	R	001000 bina	n or 09 hov	1
Bit 2	Device ID2	Device ID	R	001000 0018	IY OF US HEX	0
Bit 1	Device ID1		R			0
Bit 0	Device ID0	1	R			0

#### SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	5 Reserved						
Bit 4	BC4		RW			0	
Bit 3	BC3		RW	Writing to this regist	er will configure how	1	
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0	
Bit 1	BC1		RW	= 8 b	ytes.	0	
Bit 0	BC0		RW			0	

#### **Marking Diagrams**



Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. YYWW is the last two digits of the year and week that the part was assembled.
- 4. Line 2: truncated part number
- 5. "L" denotes RoHS compliant package.
- 6. "I" denotes industrial temperature range device.

#### **Thermal Characteristics**

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
Thermal Resistance	θ <sub>JC</sub>	Junction to Case	NDG48 37 27	33	°C/W	1
	$\theta_{Jb}$	Junction to Base		2.1	°C/W	1
	$\theta_{JA0\theta}$	Junction to Air, still air		37	°C/W	1
	θ <sub>JA1</sub>	Junction to Air, 1 m/s air flow		30	°C/W	1
	$\theta_{JA3}$	Junction to Air, 3 m/s air flow		27	°C/W	1
	$\theta_{JA5}$	Junction to Air, 5 m/s air flow		26	°C/W	1

<sup>1</sup>ePad soldered to board

### Package Outline Drawings

The package outline drawings are located at the end of this document and are accessible from the Renesas website. The package information is the most current data available and is subject to change without revision of this document.

48-VFQFPN (NDG48P1)

### **Ordering Information**

Part / Order Number	Shipping Packaging	Package	Temperature	
9DBV0841AKLF	Trays	48-pin VFQFPN	0 to +70° C	
9DBV0841AKLFT	Tape and Reel	48-pin VFQFPN	0 to +70° C	
9DBV0841AKILF	Trays	48-pin VFQFPN	-40 to +85° C	
9DBV0841AKILFT	Tape and Reel	48-pin VFQFPN	-40 to +85° C	

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

"A" is the device revision designator (will not correlate with the datasheet revision).

### **Revision History**

Revision Date	Description
	1. Removed "Differential" from DS title and Recommended Application, corrected typo's in
	Description. Updated block diagram to show integrated terminations.
	2. Removed references to 60KOhm pulldown under pinout.
	3. Updated "Phase Jitter Parameters" table by adding "Industry Limit" column and updated all
August 13, 2012	Electrical Tables with characterization data.
August 15, 2012	4. Updated Byte3[0] to be consistent with Byte 2. Updated Byte6[7:6] definition.
	5. Updated Mark spec with correct part revision (A) and added thermal data to page 13.
	6. Added NDG48 to "Package Outline and Package Dimensions" on page 14 and updated
	Ordering information to correct part revision (A rev).
	7. Move to final
	1. Changed VIH min. from 0.65*VDD to 0.75*VDD
February 18, 2013	2. Changed VIL max. from 0.35*VDD to 0.25*VDD
	3. Added missing mid-level input voltage spec (VIM) of 0.4*VDD to 0.6*VDD.
August 12, 2014	Changed package designator from "MLF" to "VFQFPN"
March 10, 2016 April 28, 2016	<ol> <li>Numerous typographical and grammatical updates for document consistency with other devices in the family, including updated descriptions for Bytes 0 and 2.</li> <li>Fast and slow slew rates were swapped in the "DIF 0.7V Low Power HCSL Outputs" table.</li> <li>Changed PCle clock source from 9FG432 to 9FGV0841/9FGL0841 for PLL mode phase jitter numbers. New phase jitter numbers are lower.</li> <li>Added epad to pinout diagram and pin descriptions.</li> <li>Updated Clock Input Parameters to be consistent with PCle Vswing parameter.</li> <li>Updated package drawing to latest format.</li> <li>Updated max frequency of 100MHz PLL mode to 140MHz</li> <li>Updated max frequency of 125MHz PLL mode to 175MHz</li> </ol>
April 28, 2016	3. Updated max frequency of 125MHz PLL mode to 175MHz 3. Updated max frequency of 50MHz PLL mode to 65MHz
August 28, 2019	Updated to PCIe Gen4.
August 20, 2019	1. Added new Electrical Characteristics–Phase Jitter Parameters tables.
July 27, 2021	2. Updated datasheet title.
	3. Updated Key Specifications.
	4. Updated Package Outline Drawings section.





6.0 x 6.0 x 0.90 mm Body, Epad 4.1x 4.1 mm, 0.40mm Pitch NDG48P1, PSC-4212-01, Rev 01, Page 1



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### **48-VFQFPN Package Outline Drawing**



6.0 x 6.0 x 0.90 mm Body, Epad 4.1 x 4.1 mm, 0.40mm Pitch NDG48P1, PSC-4212-01, Rev 01, Page 2



#### RECOMMENDED LAND PATTERN DIMENSION

#### NOTES:

- 1. ALL DIMENSION ARE IN MM. ANGLES IN DEGREES.
- 2. TOP DOWN VIEW. AS VIEWED ON PCB.
- 3. LAND PATTERN RECOMMENDATION PER IPC-7351B GENERIC REQUIREMENT FOR SURFACE MOUNT DESIGN AND LAND PATTERN.

Package Revision History				
Date Created	Rev No. Description			
Aug16, 2018	Rev 01	New Format Change QFN to VFQFPN, Recalculate Land Pattern		
May 6, 2016	Rev 00	Add Chamfer		

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